

Statistics of current fluctuations at non-zero frequencies

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We formulate a general approach which describes statistics of current fluctuations in mesoscopic coherent conductors at arbitrary frequencies and in the presence of interactions. Applying this approach to the non-interacting case, we analyze frequency dispersion of the third cumulant of the current operator $\mathcal{S}_3$ at frequencies well below both the inverse charge relaxation time and the inverse electron dwell time. This dispersion turns out to be important in the frequency range comparable to applied voltages. For comparatively transparent conductors it may lead to the sign change of $\mathcal{S}_3$.

Investigations of current fluctuations in mesoscopic conductors can provide a great deal of information about properties of such systems. During last years much attention has been devoted to shot noise¹. Experimental and theoretical studies of the second moment of the current operator describing shot noise revealed a rich variety of properties caused by an interplay between scattering, quantum coherence and charge discreteness. Furthermore, such studies can substantially deepen our understanding of the role of electron-electron interactions in mesoscopic transport because shot noise and interaction effects are known to be closely related^{2,3}.

One can also go beyond the second moment and study higher order correlators of the current operator thereby extending the amount of information already obtained from investigations of electron transport and shot noise. Recently the first experimental study of the third current cumulant in mesoscopic tunnel junctions was reported⁴.

A theoretical framework which enables one to analyze statistics of charge transfer in mesoscopic conductors was developed in Ref. 5. This theory of full counting statistics (FCS) allows to evaluate any cumulant of the current operator in the absence of interactions and in the zero frequency limit. Under these conditions higher order current cumulants were investigated by a number of authors^{6,7,8,9}. In order to include interactions and to analyze frequency dispersion of current fluctuations it is necessary to go beyond the FCS theory and to develop a more general real time path integral technique^{2,10}.

The goal of the present paper is to address statistics of current fluctuations at non-zero frequencies. We first present a general and formally exact expression for the real time effective action of a coherent conductor described by an arbitrary energy independent scattering matrix. This expression enables one to fully describe interaction effects in such type of conductors. We will then demonstrate that in a non-interacting case this effective action provides a direct generalization of the FCS generating function⁵ to non-zero frequencies. With the aid of our technique we will analyze the frequency dispersion of the third cumulant of the current operator in mesoscopic coherent conductors.

It is worthwhile to point out that the frequency dependence of current correlators can be caused by various

reasons. One of them is the effect of an external electromagnetic environment which is important for quantitative interpretation of the experimentally detected behavior of higher cumulants¹¹. Another source of the frequency dispersion is the internal dynamics of a quantum scatterer. Here the important time scales are the corresponding RC -time τ_{RC} and the electron dwell time τ_D inside the conductor. The latter scale was recently taken into consideration in the analysis of the second¹² and the third¹³ current cumulants for chaotic quantum dots.

In this paper we will address current fluctuations at frequencies not directly related to any of such scales. We will demonstrate that apart from the above mechanisms there exists an additional – intrinsic – frequency dispersion of the current correlators at the scale set by the voltage drop V across the conductor. Since V can vary in a wide range, this dependence is in general important and should be taken into account while interpreting the experimental results. In particular, in the absence of interactions the third cumulant of the current operator $\mathcal{S}_3$ is fully determined by the two parameters:

$$\beta = \frac{\sum_n T_n(1 - T_n)}{\sum_n T_n}, \quad \gamma = \frac{\sum_n T_n^2(1 - T_n)}{\sum_n T_n}, \quad (1)$$

where T_n represents the transmission of the n -th conducting channel of our system. The cumulant $\mathcal{S}_3$ can be expressed in the following general form

$$\mathcal{S}_3 = (\beta - 2\gamma F)e^2 \bar{I}. \quad (2)$$

Here $\bar{I}$ is the average current through the conductor, $-e$ stands for the electron charge, and F is a universal function of frequencies, voltage V and temperature T to be evaluated below. According to Eq. (2) the frequency dispersion of $\mathcal{S}_3$ originates only from the term proportional to the parameter γ while the β -term is dispersionless.

Though negligible for tunnel junctions $\gamma \rightarrow 0$, the frequency dispersion of $\mathcal{S}_3$ may become important in other situations. For instance, at $T \rightarrow 0$ one finds $F \rightarrow 1$ at frequencies much smaller than eV while in the opposite high frequency limit one gets $F = 0$ and, hence, $\mathcal{S}_3 = \beta e^2 \bar{I}$ in the latter limit. To give some numbers, for an important case of diffusive conductors one has $\beta = 1/3$ and $\beta - 2\gamma = 1/15$, i.e. in this case the quantity $\mathcal{S}_3$ changes

by the factor 5 depending on whether relevant frequencies are below or above eV . For conductors with $\beta < 2\gamma$ even the sign of S_3 will differ in these two limits.

In our analysis we will use the real time path integral formalism developed for the systems of interacting fermions¹⁴. After the standard Hubbard-Stratonovich decoupling of the interaction term in the Hamiltonian one can exactly integrate out fermions and arrive at the effective action S which depends on the fluctuating fields $V_{1,2}(t, \mathbf{r})$. Let us define

$$e^{iS} = \text{Tr} \left[\mathcal{T} e^{-i \int_0^t dt' \mathbf{H}_1(t')} \hat{\rho}_0 \tilde{\mathcal{T}} e^{i \int_0^t dt' \mathbf{H}_2(t')} \right], \quad (3)$$

with the trace taken over the fermionic variables. Here $\hat{\rho}_0$ is the initial N -particle density matrix of electrons,

$$\begin{aligned} \mathbf{H}_{1,2} &= \sum_{\sigma} \int d^3 \mathbf{r} \hat{\Psi}_{\sigma}^{\dagger}(\mathbf{r}) \hat{H}_{1,2}(t) \hat{\Psi}_{\sigma}(\mathbf{r}), \\ \hat{H}_{1,2}(t) &= -\frac{\nabla^2}{2m} + U(\mathbf{r}) - eV_{1,2}(t, \mathbf{r}) \end{aligned} \quad (4)$$

are the effective Hamiltonians on the forward and backward parts of the Keldysh contour, $U(\mathbf{r})$ describes the static potential, $\mathcal{T}$ and $\tilde{\mathcal{T}}$ are respectively the forward and backward time ordering operators. Integrating out fermions in Eq. (3), we obtain $iS = iS_0 + iS_{\text{em}}$ where

$$iS_0 = 2 \text{Tr} \ln [1 + (\hat{u}_2^{-1} \hat{u}_1 - 1) \hat{\rho}_0], \quad (5)$$

$\hat{u}_{1,2}(t) = \mathcal{T} \exp \left(-i \int_0^t dt' \hat{H}_{1,2}(t') \right)$ are the evolution operators pertaining to the Hamiltonians (4), $\hat{\rho}_0$ stands for

the initial single-particle density matrix and the term S_{em} accounts for the electromagnetic contribution which may also include the effect of an external circuit.

In order to evaluate the evolution operators $\hat{u}_{1,2}$ it is necessary to specify the model of a mesoscopic conductor. Here we will adopt the standard model of a (comparatively short) coherent conductor placed in-between two bulk metallic reservoirs. The electron dwell time τ_D is supposed to be shorter than any relevant time scale in our problem. Energy and phase relaxation times are, on the contrary, assumed to be long, i.e. inelastic relaxation is allowed in the reservoirs but not inside the conductor. Under these assumptions electron transport through the conductor can be described by the energy independent scattering matrix

$$\hat{S} = \begin{pmatrix} \hat{r} & \hat{t}' \\ \hat{t} & \hat{r}' \end{pmatrix} \quad (6)$$

and the effective action (5) can be expressed via the fluctuating phase fields $\varphi_{1,2}$ which are in turn related to the jumps of the fields $V_{1,2}$ across the scatterer as $\dot{\varphi}_{1,2} = e(V_{L1,2} - V_{R1,2})$, where $V_{L,R}$ are fluctuating in time but constant in space fields in the left and right reservoirs. We note that in this case the right hand side of Eq. (3) differs from the FCS generating functional introduced in Ref. 15 only by a gauge transformation.

Within the above model the evolution operators $\hat{u}_{1,2}$ were evaluated in Refs. 2,10. Combining these expressions with Eq. (5) after some algebra we find

$$iS_0 = 2 \text{Tr} \ln \left\{ \hat{1} \delta(x-y) + \theta(t-x) \theta(x) \begin{bmatrix} \hat{t}^{\dagger} \hat{t} (e^{i\varphi^{-}(x)} - 1) & 2i\hat{t}^{\dagger} \hat{r}' \sin \frac{\varphi^{-}(x)}{2} \\ 2i\hat{r}^{\dagger} \hat{t} \sin \frac{\varphi^{-}(x)}{2} & \hat{t}^{\dagger} \hat{t}' (e^{-i\varphi^{-}(x)} - 1) \end{bmatrix} \begin{bmatrix} \rho_0(y-x) e^{i\frac{\varphi^{+}(x)-\varphi^{+}(y)}{2}} & 0 \\ 0 & \rho_0(y-x) e^{i\frac{\varphi^{+}(y)-\varphi^{+}(x)}{2}} \end{bmatrix} \right\}. \quad (7)$$

Here we introduced $\varphi^{+} = (\varphi_1 + \varphi_2)/2$, $\varphi^{-} = \varphi_1 - \varphi_2$ and

$$\rho_0(x) = \int \frac{dE}{2\pi} \frac{e^{iEx}}{1 + e^{E/T}}. \quad (8)$$

Taking the trace in Eq. (7) implies convolution with respect to internal time variables (x and y). The total time span is denoted by t .

Eq. (7) defines a formally exact effective action for a coherent conductor described by an arbitrary energy independent scattering matrix (6). This expression allows to fully determine statistics of current fluctuations at arbitrary frequencies and in the presence of interactions. In the case of equilibrium fluctuations the formula (7) represents a real time analogue of the effective action derived in Refs. 16,17 within the Matsubara technique. A formula similar to Eq. (7) was also presented recently

in Ref. 18. In addition we note that, provided the field φ^{-} does not depend on time, Eq. (7) coincides with the generating function considered, e.g., in the problem of adiabatic pumping through mesoscopic conductors¹⁹.

Let us illustrate the relation between the effective action (7) and the FCS generating function⁵. For this purpose we (i) disregard interactions and set $\varphi^{+}(t) = eVt$ and (ii) suppress fluctuations of φ^{-} and set $\varphi^{-} = \text{const}$. After these simplifications from Eq. (7) we obtain

$$\begin{aligned} iS_{FCS} &= \frac{t}{\pi} \text{Tr} \int dE \ln \left[1 + \hat{t}^{\dagger} \hat{t} n_L(E) (1 - n_R(E)) \right. \\ &\quad \left. \times (e^{i\varphi^{-}} - 1) + \hat{t}^{\dagger} \hat{t} n_R(E) (1 - n_L(E)) (e^{-i\varphi^{-}} - 1) \right], \end{aligned} \quad (9)$$

where $n_{L,R}(E) = 1/[1 + \exp[(E \pm eV/2)/T]]$. Eq. (9) is just the FCS generating function⁵ which can be used to recover all cumulants of the current operator in the zero

frequency limit and in the absence of interactions.

The expression (7) is more general since it includes all possible fluctuations of the phase fields $\varphi^\pm$. For instance, if one allows for temporal variations of φ^- , with the aid of Eq. (7) one can easily describe the frequency dispersion of the current correlators. Below we will illustrate this point by directly evaluating the third cumulant of the current operator.

Within our model the current operator can be defined in a standard manner

$$\hat{I}(t) = \frac{e}{2} \frac{d}{dt} (\hat{N}_L(t) - \hat{N}_R(t)), \quad (10)$$

where $\hat{N}_{L(R)}$ is the total number of electrons in the left (right) lead. Combining this definition with Eq. (3) for the expectation value one finds

$$\langle \hat{I}(t) \rangle = -e \int \mathcal{D}\varphi^\pm \delta S[\varphi^\pm] / \delta \varphi^-(t) e^{iS[\varphi^\pm]}.$$

Similarly one can define higher moments of the current operator. Here we consider the following correlation functions: $\tilde{\mathcal{S}}_2 = \langle \hat{I}(t_1) \hat{I}(t_2) + \hat{I}(t_2) \hat{I}(t_1) \rangle / 2$ and

$$\begin{aligned} \tilde{\mathcal{S}}_3 = & \frac{1}{8} \{ \langle \hat{I}(t_1) (\mathcal{T} \hat{I}(t_2) \hat{I}(t_3)) \rangle + \langle (\tilde{\mathcal{T}} \hat{I}(t_2) \hat{I}(t_3)) \hat{I}(t_1) \rangle \\ & + \langle \hat{I}(t_2) (\mathcal{T} \hat{I}(t_1) \hat{I}(t_3)) \rangle + \langle (\tilde{\mathcal{T}} \hat{I}(t_1) \hat{I}(t_3)) \hat{I}(t_2) \rangle \\ & + \langle \hat{I}(t_3) (\mathcal{T} \hat{I}(t_1) \hat{I}(t_2)) \rangle + \langle (\tilde{\mathcal{T}} \hat{I}(t_1) \hat{I}(t_2)) \hat{I}(t_3) \rangle \\ & + \langle \mathcal{T} \hat{I}(t_1) \hat{I}(t_2) \hat{I}(t_3) \rangle + \langle \tilde{\mathcal{T}} \hat{I}(t_1) \hat{I}(t_2) \hat{I}(t_3) \rangle \}. \quad (11) \end{aligned}$$

The correlation function $\tilde{\mathcal{S}}_2$ is important because the symmetric combination of voltages V^+ can be viewed as a classical, measurable, voltage¹⁵. The noise is deduced from the measurable product $V^+(t_1)V^+(t_2)$, which is related to the symmetric correlator $\tilde{\mathcal{S}}_2$. Similarly, the measured product $V^+(t_1)V^+(t_2)V^+(t_3)$ is related to the correlation function of the current operators $\tilde{\mathcal{S}}_3$ defined in Eq. (11), see also Refs. 9,15.

Let us now disregard interaction effects. In this case one should suppress fluctuations of $\varphi^\pm$ in the end of the calculation by setting $\varphi^+(\tau) = eV\tau$ and $\varphi^-(\tau) \rightarrow 0$. Then for the noise correlator one easily finds

$$\tilde{\mathcal{S}}_2 = (ie)^2 \frac{\delta^2}{\delta \varphi^-(t_1) \delta \varphi^-(t_2)} e^{iS_0} \Big|_{\varphi^-=0} \quad (12)$$

and a similar expression is obtained for $\tilde{\mathcal{S}}_3$. Of interest is the irreducible part of the correlator $\tilde{\mathcal{S}}_3$ which reads

$$\begin{aligned} \mathcal{S}_3 = & e^3 \frac{\delta^3 S_0}{\delta \varphi^-(t_1) \delta \varphi^-(t_2) \delta \varphi^-(t_3)} \Big|_{\varphi^-=0} \quad (13) \\ = & \tilde{\mathcal{S}}_3(t_1, t_2, t_3) - \langle \hat{I}(t_1) \rangle \tilde{\mathcal{S}}(t_2, t_3) - \langle \hat{I}(t_2) \rangle \tilde{\mathcal{S}}(t_1, t_3) \\ & - \langle \hat{I}(t_3) \rangle \tilde{\mathcal{S}}(t_1, t_2) + 2 \langle \hat{I}(t_1) \rangle \langle \hat{I}(t_2) \rangle \langle \hat{I}(t_3) \rangle. \end{aligned}$$

It follows immediately that in order to evaluate the third current cumulant in the absence of interactions it suffices

to expand the exact effective action (7) up to the third order in φ^- ,

$$iS_0[\varphi^\pm] = iS^{(1)}[\varphi^\pm] + iS^{(2)}[\varphi^\pm] + iS^{(3)}[\varphi^\pm], \quad (14)$$

keeping the full non-linearity in φ^+ in each of these terms. The first two terms of this expansion were evaluated in Ref. 2. Being combined with Eq. (12), the term $S^{(2)}[\varphi^\pm]$ allows to recover the well known expression for the shot noise spectrum¹. Proceeding further with the expansion in φ^- for the term $iS^{(3)}$ one finds¹⁰

$$\begin{aligned} iS^{(3)}[\varphi^\pm] = & \frac{i\beta}{6e^2 R} \int_0^t d\tau (\varphi^-(\tau))^3 \dot{\varphi}^+(\tau) \quad (15) \\ & - \frac{2\pi i\gamma}{3e^2 R} \int_0^t d\tau_1 \int_0^t d\tau_2 \int_0^t d\tau_3 \varphi^-(\tau_1) \varphi^-(\tau_2) \varphi^-(\tau_3) \\ & \times f(\tau_2, \tau_1) f(\tau_3, \tau_2) f(\tau_1, \tau_3), \end{aligned}$$

where $1/R = (2e^2/h) \sum_n T_n$ is the scatterer conductance and

$$f(\tau_2, \tau_1) = \frac{T \sin[(\varphi^+(\tau_2) - \varphi^+(\tau_1))/2]}{\sinh[\pi T(\tau_2 - \tau_1)]}. \quad (16)$$

Let us substitute the above expressions into Eq. (13) and, after taking derivatives over φ^- , set $\varphi^+(\tau) = eV\tau$ and $\varphi^- \rightarrow 0$. This is sufficient provided the time differences $|t_1 - t_2|$, $|t_1 - t_3|$ exceed the charge relaxation time τ_{RC} and provided $eV \ll 1/\tau_{RC}$. The formula (13) immediately yields

$$\begin{aligned} \mathcal{S}_3 = & \beta e^2 \bar{I} \delta(t_1 - t_2) \delta(t_1 - t_3) \quad (17) \\ & - \frac{4\pi e\gamma}{R} f(t_2 - t_1) f(t_3 - t_2) f(t_1 - t_3), \end{aligned}$$

where $f(\tau) = T \sin(eV\tau/2) / \sinh(\pi T\tau)$. Performing the Fourier transformation

$$\mathcal{S}_3(\omega_1, \omega_2) = \int d\tau_1 d\tau_2 e^{i\omega_1 \tau_1 + i\omega_2 \tau_2} \mathcal{S}_3(t_1, t_1 - \tau_1, t_1 - \tau_2)$$

we arrive at the final result

$$\mathcal{S}_3 = \beta e^2 \bar{I} - 2\gamma e^2 \bar{I} F(v, w_1, w_2), \quad (18)$$

where

$$F = \frac{\sinh^3(v/2)}{4v} \int_{-\infty}^{\infty} \frac{d\omega}{\chi(\omega) \chi(\omega - w_1) \chi(\omega + w_2)}. \quad (19)$$

Here we defined $v = eV/T$, $w_{1,2} = \omega_{1,2}/2T$ and

$$\chi(\omega) = \cosh^2 \omega + \sinh^2(v/4). \quad (20)$$

Eqs. (18)-(20) represent the main result of this paper. They fully describe the third cumulant of the current operator at voltages and frequencies smaller than both $1/\tau_{RC}$ and $1/\tau_D$.

Let us briefly analyze Eqs. (18)-(20) in various limits. For $\omega_{1,2} = 0$ we recover the well known result⁷

$$F(v, 0, 0) = 1 + 3 \frac{1 - (\sinh v/v)}{\cosh v - 1}, \quad (21)$$

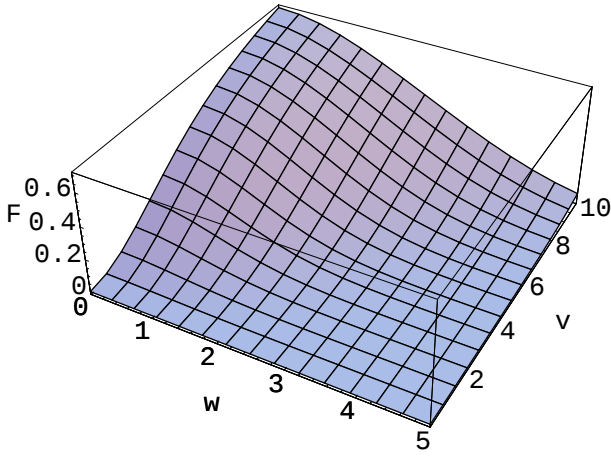


FIG. 1: The function $F(v, w, 0) = F(v, w, -w)$, see Eq. (19).

which in turn yields $F \rightarrow 1$ in the limit of large voltages $v \gg 1$. Eq. (21) also holds for $w_{1,2} \ll v$.

In the limit $v \ll 1$ one finds

$$F(v \ll 1, w, 0) = F(v \ll 1, w, -w) = \frac{9 \sinh w + \sinh(3w) - 12w \cosh w}{48 \sinh^5 w} v^2 \quad (22)$$

and, similarly,

$$F(v \ll 1, w, w) = \frac{\sinh(4w) + 4 \sinh(2w) - 8w \cosh(2w) - 4w}{128 \sinh^5 w \cosh^3 w} v^2. \quad (23)$$

These equations demonstrate that at large frequencies $w \gg 1$ the function F decays exponentially with w . From Eqs. (22) and (23) we find respectively $F \propto v^2 e^{-2w}/3$ and $F \propto v^2 e^{-4w}$.

Finally let us turn to the most interesting limit of low temperatures, in which case one always has $v, w_1, w_2 \gg 1$. Neglecting small corrections $\sim 1/v, 1/w$ we obtain

$$F(v, w_1, w_2) = 1 - 2 \left| \frac{w_{12}}{v} \right|, \quad \text{if } 2|w_{12}| < |v| \quad (24)$$

$$F(v, w_1, w_2) = 0, \quad \text{if } 2|w_{12}| > |v|. \quad (25)$$

Here the value w_{12} is defined differently depending on the sign of the product $w_1 w_2$. For $w_1 w_2 > 0$ we have $w_{12} = w_1 + w_2$ while in the opposite case $w_1 w_2 < 0$ we define $w_{12} = \max[|w_1|, |w_2|]$. We observe that in both cases the function F depends linearly on frequency and vanishes as soon as $|w_{12}|$ exceeds $|v|/2$.

At arbitrary values of v, w_1 and w_2 the integral (19) can be evaluated numerically. The corresponding result for the function $F(v, w, 0)$ is depicted in Fig. 1. The overall form of the function $F(v, w, w)$ is similar but – as compared to $F(v, w, 0)$ – it demonstrates a somewhat faster decay with increasing frequency.

In conclusion, we have presented a general approach which allows to describe statistics of current fluctuations in mesoscopic coherent conductors at arbitrary frequencies and in the presence of interactions. Restricting ourselves to the non-interacting case, we have analyzed frequency dispersion of the third cumulant of the current operator. This dispersion was found negligible only in the case of tunnel junctions, while in a general case it turns out to be important in the frequency range comparable to eV . Similar results are also expected for higher order cumulants of the current operator.

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